

DIFFERENTIAL COMPARATOR

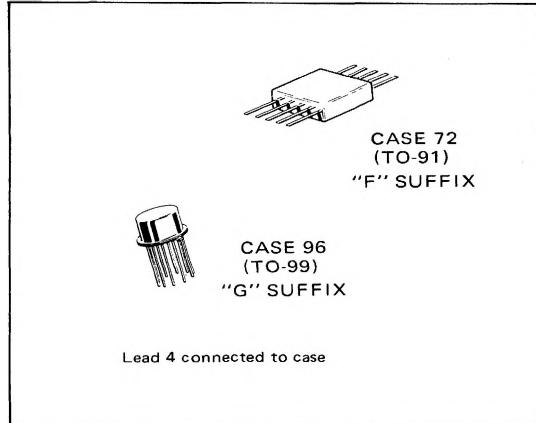
SENSE AMPLIFIERS

MC1710

. . . designed for use in level detection, low-level sensing, and memory applications.

Typical Amplifier Features:

- Differential Input Characteristics:
Input Offset Voltage = 1.0 mV
Offset Voltage Drift = 3.0 μ V/ $^{\circ}$ C
- Fast Response Time – 40 ns
- Output Compatible with All Saturating Logic Forms
 V_{out} = +3.2 V to -0.5 V typical
- Low Output Impedance – 200 ohms

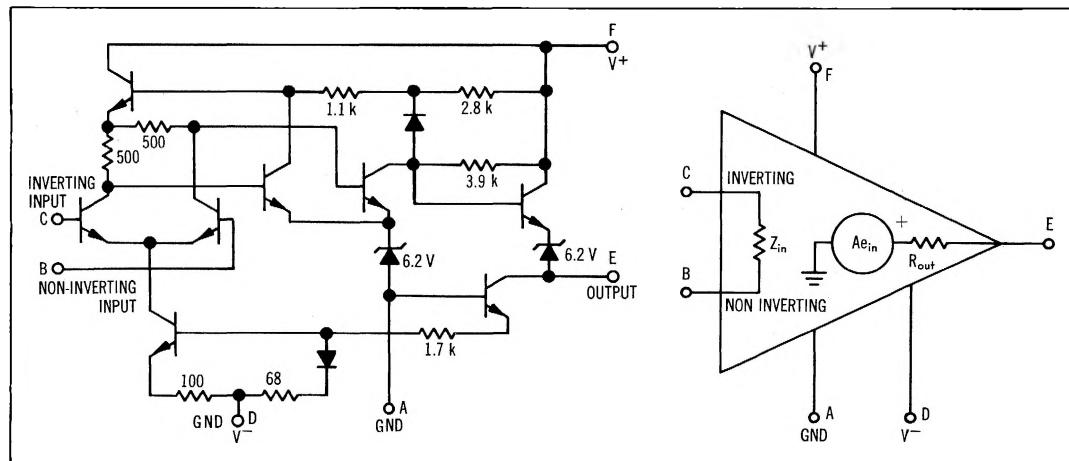
MAXIMUM RATINGS ($T_A = 25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Value	Unit
Power Supply Voltage	V^+ V^-	+ 14 - 7.0	Vdc Vdc
Differential Input Signal	V_{in}	± 5.0	Volts
Common Mode Input Swing	CMV_{in}	± 7.0	Volts
Peak Load Current	I_L	10	mA
Power Dissipation (package limitation)	P_D		
Metal Can Derate above $T_A = 25^{\circ}$ C		680 4.6	mW mW/ $^{\circ}$ C
Flat Package Derate above $T_A = 25^{\circ}$ C		500 3.3	mW mW/ $^{\circ}$ C
Operating Temperature Range	T_A	-55 to +125	$^{\circ}$ C
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}$ C

PIN CONNECTIONS

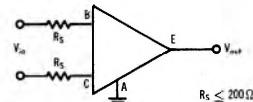
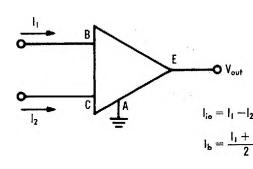
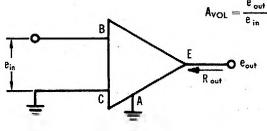
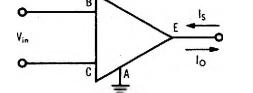
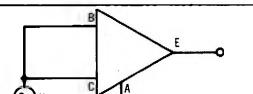
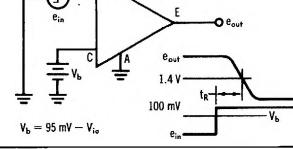
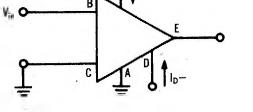
Schematic	A	B	C	D	E	F
"G" Package	1	2	3	4	7	8
"F" Package	1	2	3	5	6	8

CIRCUIT SCHEMATIC



MC1710 (continued)

ELECTRICAL CHARACTERISTICS ($V^+ = +12 \text{ Vdc}$, $V^- = -6 \text{ Vdc}$, $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic Definitions	Characteristic	Symbol	Min	Typ	Max	Unit
 $R_S \leq 200\Omega$	Input Offset Voltage $V_{out} = 1.4 \text{ Vdc}, T_A = 25^\circ\text{C}$ $V_{out} = 1.8 \text{ Vdc}, T_A = -55^\circ\text{C}$ $V_{out} = 1.0 \text{ Vdc}, T_A = +125^\circ\text{C}$	V_{IO}	-	1.0	2.0	mVdc
	Temperature Coefficient of Input Offset Voltage	TC_{VIO}	-	3.0	-	$\mu\text{V}/^\circ\text{C}$
 $I_{IO} = I_1 - I_2$ $I_B = \frac{I_1 + I_2}{2}$	Input Offset Current $V_{out} = 1.4 \text{ Vdc}, T_A = 25^\circ\text{C}$ $V_{out} = 1.8 \text{ Vdc}, T_A = -55^\circ\text{C}$ $V_{out} = 1.0 \text{ Vdc}, T_A = +125^\circ\text{C}$	I_{IO}	-	1.0	3.0	μAdc
	Input Bias Current $V_{out} = 1.4 \text{ Vdc}, T_A = 25^\circ\text{C}$ $V_{out} = 1.8 \text{ Vdc}, T_A = -55^\circ\text{C}$ $V_{out} = 1.0 \text{ Vdc}, T_A = +125^\circ\text{C}$	I_B	-	12	20	μAdc
 $A_{VOL} = \frac{e_{out}}{e_{in}}$	Open Loop Voltage Gain $T_A = 25^\circ\text{C}$ $T_A = -55 \text{ to } +125^\circ\text{C}$	A_{VOL}	1250 1000	1700	-	V/V
	Output Resistance	R_{out}	-	200	-	ohms
	Differential Voltage Range	V_{in}	± 5.0	-	-	Vdc
	Positive Output Voltage $V_{in} \geq 5.0 \text{ mV}, 0 \leq I_o \leq 0.5 \text{ mA}$	V_{OH}	2.5	3.2	4.0	Vdc
	Negative Output Voltage $V_{in} \geq -5.0 \text{ mV}$	V_{OL}	-1.0	-0.5	0	Vdc
	Output Sink Current $V_{in} \geq -5.0 \text{ mV}, V_{out} \geq 0, T_A = 25^\circ\text{C}$ $V_{in} \geq -5.0 \text{ mV}, V_{out} \geq 0, T_A = -55^\circ\text{C}$	I_S	2.0 1.0	2.5 2.0	-	mAdc
	Input Common Mode Range	CMV_{in}	± 5.0	-	-	Volts
	Common Mode Rejection Ratio $V^- = -7.0 \text{ Vdc}, R_S \leq 200\Omega$	CM_{rej}	80	100	-	dB
 $V_b = 95 \text{ mV} - V_{IO}$	Response Time For Positive and Negative Going Input Pulse	t_R	-	40	-	ns
	Power Supply Current $V_{out} \leq 0 \text{ Vdc}$	I_D^+ I_D^-	-	6.4 5.5	9.0 7.0	mAdc
	Power Consumption TO-99 Metal Can TO-91 Flat Package		-	115 115	150 150	mW

MC1710 (continued)

TYPICAL CHARACTERISTICS

FIGURE 1 – VOLTAGE TRANSFER CHARACTERISTICS

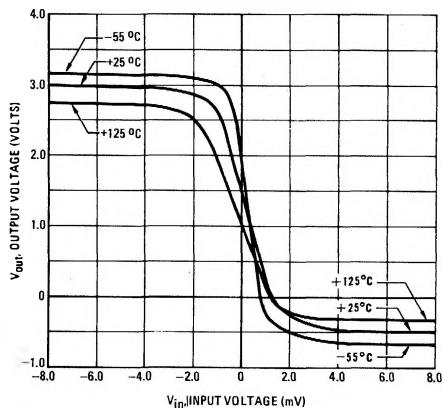


FIGURE 2 – INPUT OFFSET VOLTAGE versus TEMPERATURE

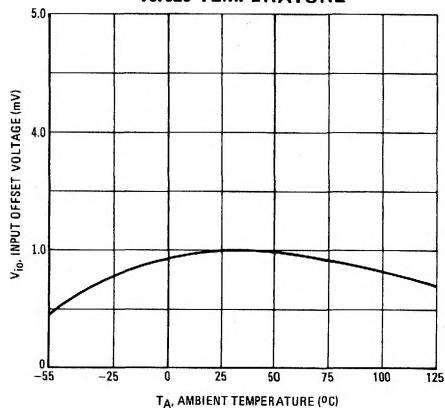


FIGURE 3 – INPUT OFFSET CURRENT versus TEMPERATURE

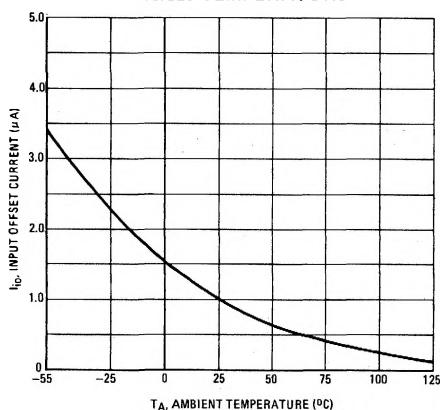


FIGURE 4 – INPUT BIAS CURRENT versus TEMPERATURE

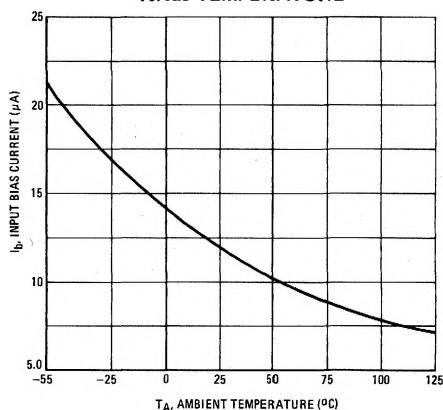


FIGURE 5 – GAIN VARIATION WITH POWER SUPPLY VOLTAGE

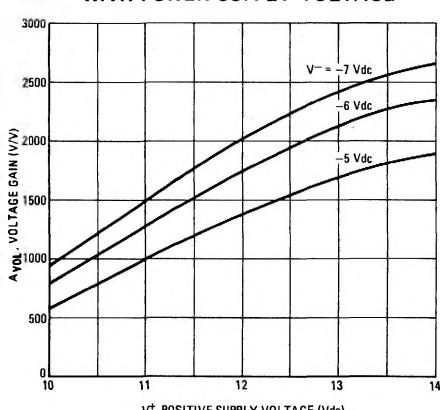
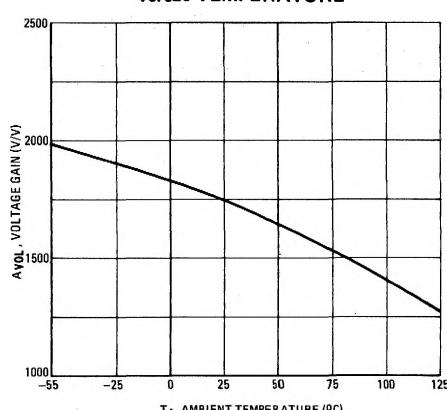


FIGURE 6 – VOLTAGE GAIN versus TEMPERATURE



MC1710 (continued)

FIGURE 7 – RESPONSE TIME

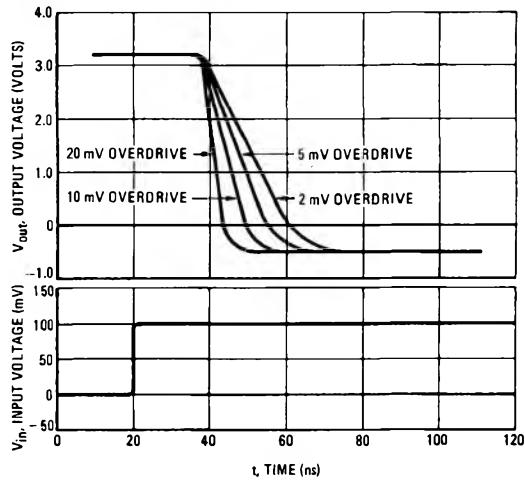


FIGURE 8 – POWER DISSIPATION versus TEMPERATURE

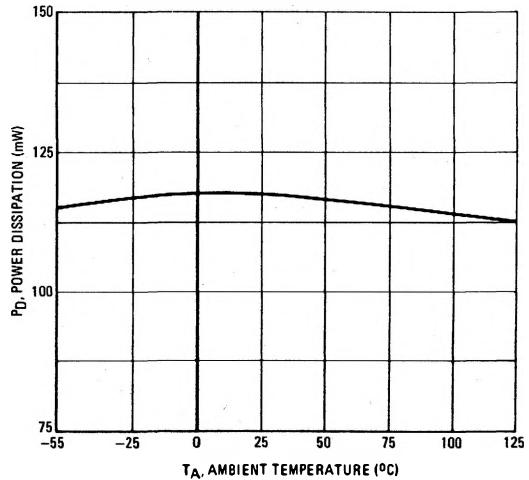


FIGURE 9 – SERIES RESISTANCE versus MRTL FAN-OUTS

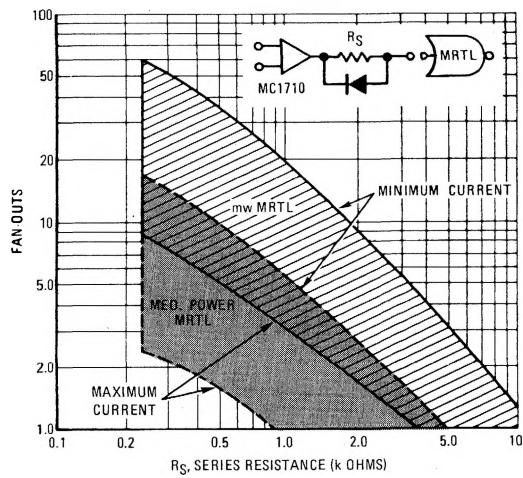


FIGURE 10 – FAN-OUT CAPABILITY WITH MDTL OR MTTL OUTPUT SWING

